

74F245

Octal Bidirectional Transceiver with 3-STATE Outputs

Features

- Non-inverting buffers
- Bidirectional data path
- A outputs sink 24mA
- B outputs sink 64mA

General Description

The 74F245 contains eight non-inverting bidirectional buffers with 3-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 24mA at the A Ports and 64mA at the B Ports. The Transmit/Receive ($T/\bar{R}$) input determines the direction of data flow through the bidirectional transceiver. Transmit (active HIGH) enables data from A Ports to B Ports; Receive (active LOW) enables data from B Ports to A Ports. The Output Enable input, when HIGH, disables both A and B Ports by placing them in a High Z condition.

Ordering Information

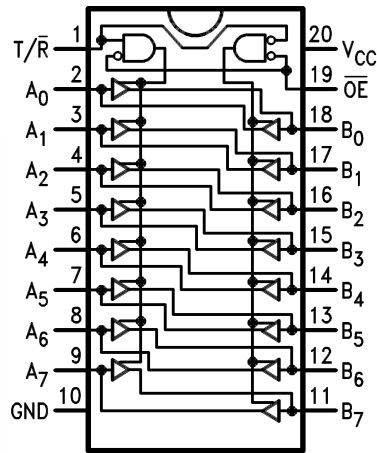
Order Number	Package Number	Package Description
74F245SC	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide
74F245SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74F245MSA	MSA20	20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide
74F245MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74F245PC	N20A	20-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300" Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

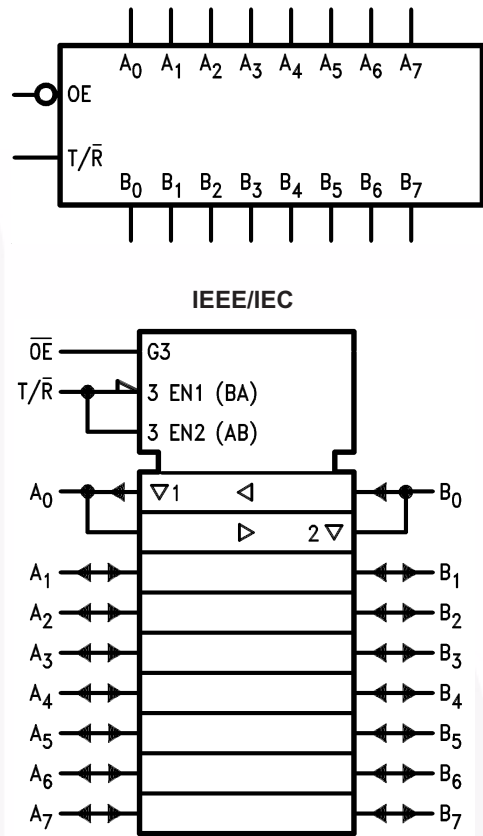


All packages are lead free per JEDEC: J-STD-020B standard.

Connection Diagram



Logic Symbols



Truth Table

Inputs		Output
OE	T/R	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	High Z State

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial

Unit Loading/Fan Out

Pin Names	Description	U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
OE	Output Enable Input (Active LOW)	1.0/2.0	20 μ A/-1.2mA
T/R	Transmit/Receive Input	1.0/2.0	20 μ A/-1.2mA
A ₀ -A ₇	Side A Inputs or 3-STATE Outputs	3.5/1.083 150/40 (38.3)	70 μ A/-0.65mA -3 mA/24mA (20mA)
B ₀ -B ₇	Side B Inputs or 3-STATE Outputs	3.5/1.083 600/106.6 (80)	70 μ A/-0.65mA -12mA/64mA (48mA)

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
T_{STG}	Storage Temperature	–65°C to +150°C
T_A	Ambient Temperature Under Bias	–55°C to +125°C
T_J	Junction Temperature Under Bias	–55°C to +150°C
V_{CC}	V_{CC} Pin Potential to Ground Pin	–0.5V to +7.0V
V_I	Input Voltage ⁽¹⁾	–0.5V to +7.0V
I_I	Input Current ⁽¹⁾	–30mA to +5.0mA
	Voltage Applied to Output in HIGH State (with $V_{CC} = 0V$)	
	Standard Output	–0.5V to V_{CC}
	3-STATE Output	–0.5V to +5.5V
	Current Applied to Output in LOW State (Max.)	twice the rated I_{OL} (mA)
	ESD Last Passing Voltage (Min.)	4000V

Note:

1. Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
T_A	Free Air Ambient Temperature	0°C to +70°C
V_{CC}	Supply Voltage	+4.5V to +5.5V

DC Electrical Characteristics

Symbol	Parameter		V _{CC}	Conditions	Min.	Typ.	Max.	Units
V _{IH}	Input HIGH Voltage			Recognized as a HIGH Signal	2.0			V
V _{IL}	Input LOW Voltage			Recognized as a LOW Signal			0.8	V
V _{CD}	Input Clamp Diode Voltage		Min.	I _{IN} = -18mA			-1.2	V
V _{OH}	Output HIGH Voltage	10% V _{CC}	Min.	I _{OH} = -3mA (A _n)	2.4			V
		10% V _{CC}		I _{OH} = -15mA (B _n)	2.0			
		5% V _{CC}		I _{OH} = -3mA (A _n)	2.7			
V _{OL}	Output LOW Voltage	10% V _{CC}	Min.	I _{OL} = 24mA (A _n)			0.5	V
		10% V _{CC}		I _{OL} = 64mA (B _n)			0.55	
I _{IH}	Input HIGH Current		Max.	V _{IN} = 2.7V			5.0	μA
I _{BVI}	Input HIGH Current Breakdown Test		Max.	V _{IN} = 7.0V ($\overline{OE}$, T/ $\overline{R}$)			7.0	μA
I _{BVIT}	Input HIGH Current Breakdown (I/O)		Max.	V _{IN} = 5.5V (A _n , B _n)			0.5	mA
I _{CEX}	Output HIGH Leakage Current		Max.	V _{OUT} = V _{CC} (A _n , B _n)			50	μA
V _{ID}	Input Leakage Test		0.0	I _{ID} = 1.9μA, All Other Pins Grounded	4.75			V
I _{OD}	Output Leakage Circuit Current		0.0	V _{IOD} = 150mV, All Other Pins Grounded			3.75	μA
I _{IL}	Input LOW Current		Max.	V _{IN} = 0.5V (T/ $\overline{R}$, $\overline{OE}$)			-1.2	mA
I _{IH} + I _{OZH}	Output Leakage Current		Max.	V _{OUT} = 2.7V (A _n , B _n)			70	μA
I _{IL} + I _{OZL}	Output Leakage Current		Max.	V _{OUT} = 0.5V (A _n , B _n)			-650	μA
I _{OS}	Output Short-Circuit Current		Max.	V _{OUT} = 0V (A _n)	-60		-150	mA
				V _{OUT} = 0V (B _n)	-100		-225	
I _{ZZ}	Bus Drainage Test		0.0V	V _{OUT} = 5.25V (A _n , B _n)			500	μA
I _{CCH}	Power Supply Current		Max.	V _O = HIGH		70	90	mA
I _{CCL}	Power Supply Current		Max.	V _O = LOW		95	120	mA
I _{CCZ}	Power Supply Current		Max.	V _O = HIGH Z		85	110	mA

AC Electrical Characteristics

Symbol	Parameter	$T_A = +25^{\circ}\text{C}$, $V_{CC} = +5.0\text{V}$, $C_L = 50\text{pF}$			$T_A = -55^{\circ}\text{C to } +125^{\circ}\text{C}$, $C_L = 50\text{pF}$		$T_A = 0^{\circ}\text{C to } +70^{\circ}\text{C}$, $C_L = 50\text{pF}$		Units
		Min.	Typ.	Max.	Min.	Max.	Min.	Max.	
t_{PLH} , t_{PHL}	Propagation Delay, A_n to B_n or B_n to A_n	2.5	4.2	6.0	2.0	7.5	2.0	7.0	ns
		2.5	4.2	6.0	2.0	7.5	2.0	7.0	
t_{PZH} , t_{PZL}	Output Enable Time	3.0	5.3	7.0	2.5	9.0	2.5	8.0	ns
		3.5	6.0	8.0	3.0	10.0	3.0	9.0	
t_{PHZ} , t_{PLZ}	Output Disable Time	2.0	5.0	6.5	2.0	9.0	2.0	7.5	ns
		2.0	5.0	6.5	2.0	10.0	2.0	7.5	

Physical Dimensions

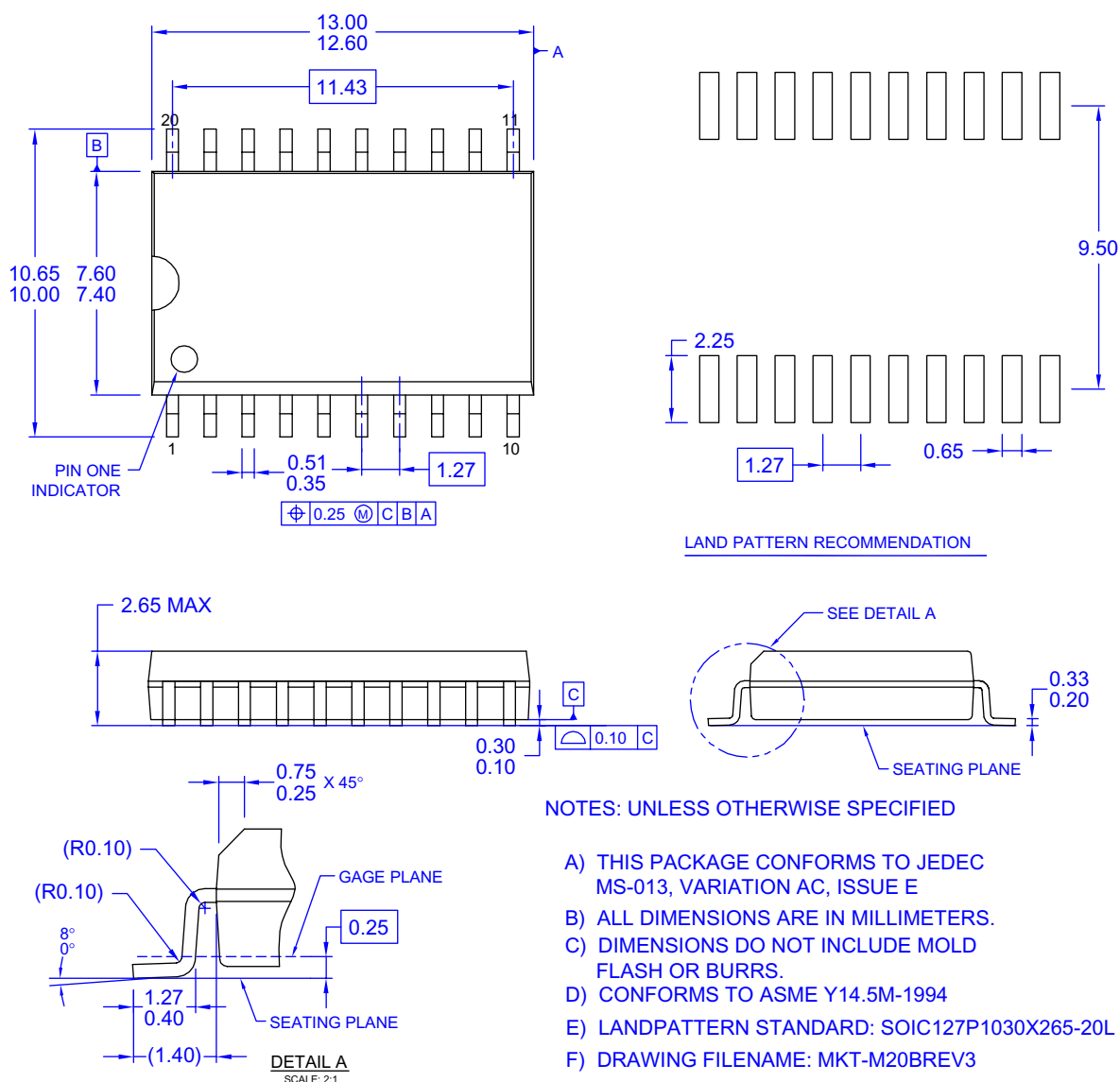


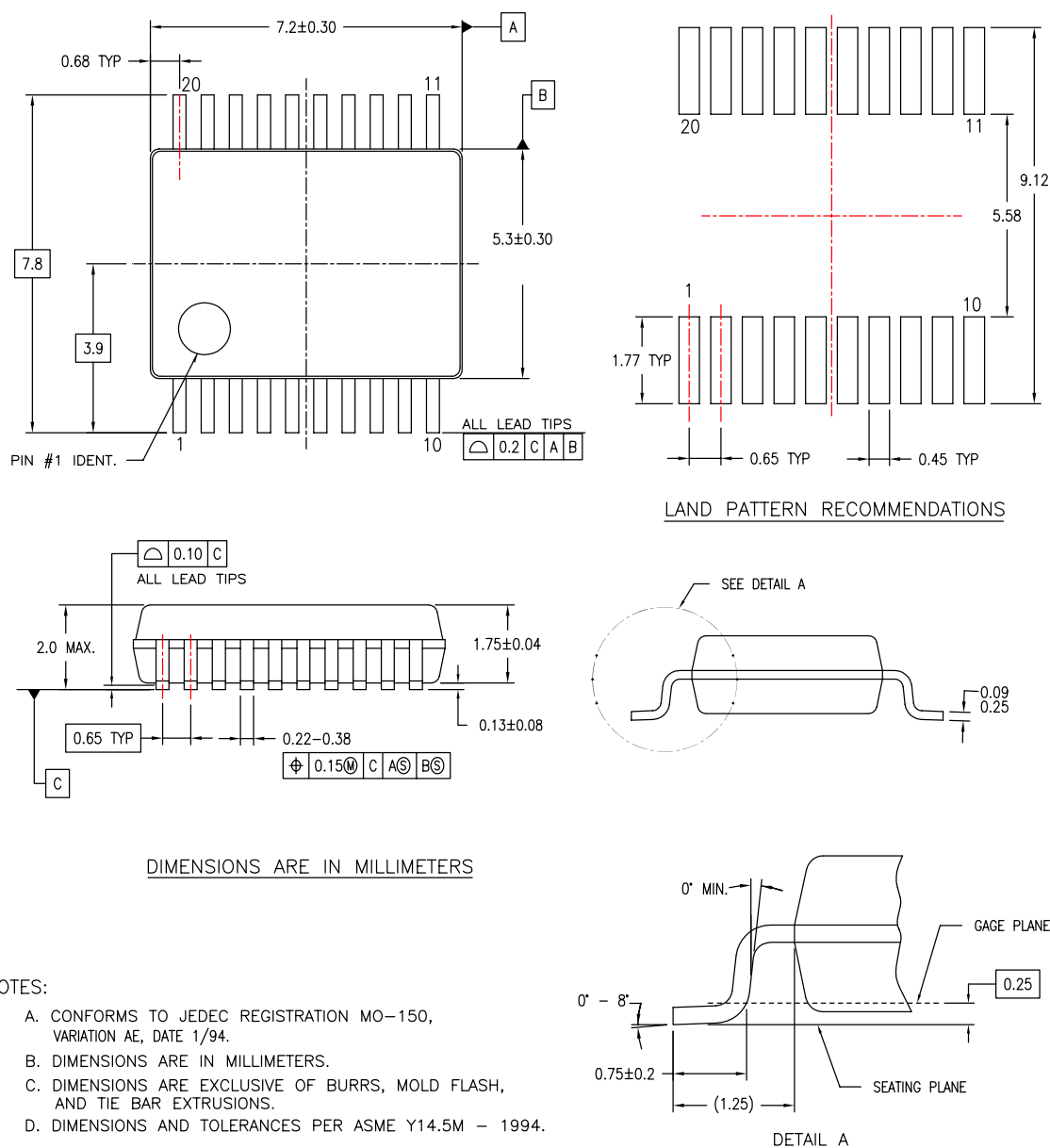
Figure 1. 20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300" Wide

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Physical Dimensions (Continued)



NOTES:

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- DIMENSIONS AND TOLERANCES PER ASME Y14.5M - 1994.

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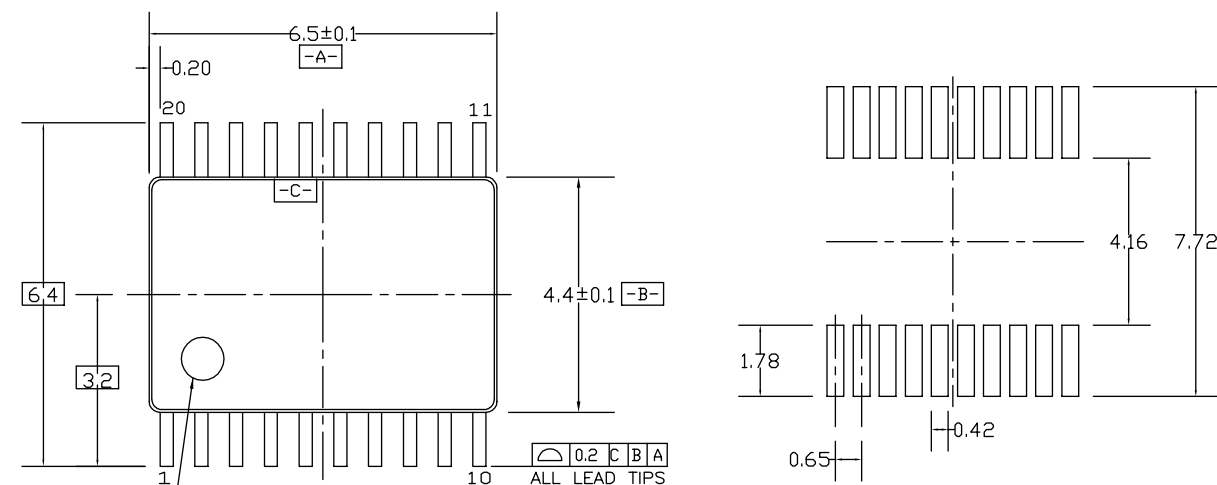
Figure 3. 20-Lead Shrink Small Outline Package (SSOP), JEDEC MO-150, 5.3mm Wide

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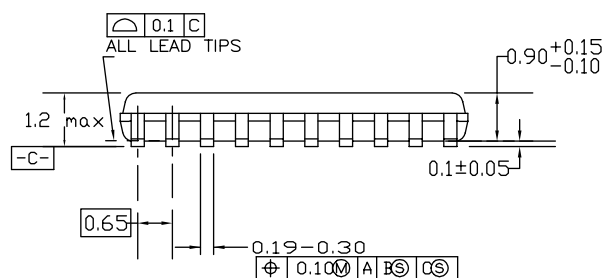
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Physical Dimensions (Continued)



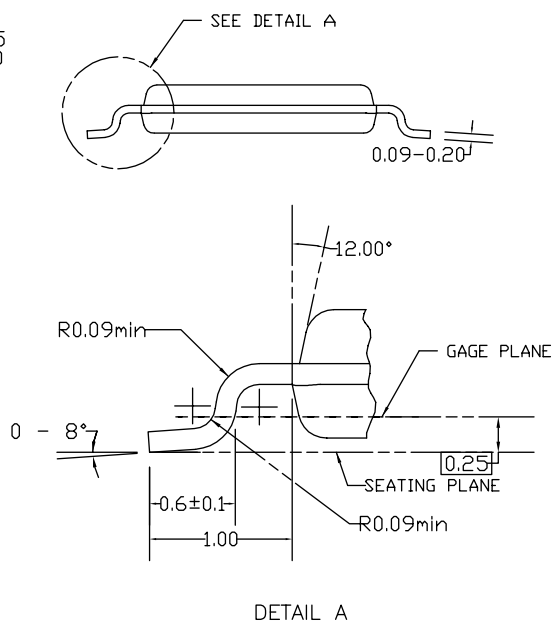
LAND PATTERN RECOMMENDATION



DIMENSIONS ARE IN MILLIMETERS

NOTES:

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DETAIL A

MTC20REV D1

Figure 4. 20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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